Photo Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal and plastic
Overall Length:
Between 0.200 inches and 0.250 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 collector to emitter voltage/static/base open and 80.0 collector to base voltage/static/emitter open
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector preset
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0